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High Voltage Surface Mount Input Rectifier Diode, 20 A

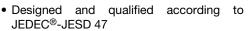


- 2			
D ² PAK	(TO-	263/	٩В

PRIMARY CHARACTERISTICS						
I _{F(AV)} 20 A						
V_{R}	800 V, 1200 V					
V _F at I _F	1.1 V					
I _{FSM}	300 A					
T _J max.	150 °C					
Package	D ² PAK (TO-263AB)					
Circuit configuration	Single					

FEATURES

- · Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C



 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



APPLICATIONS

- Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-20ETS...S-M3 rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS							
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS							
Capacitive input filter T _A = 55 °C, T _J = 125 °C common heatsink of 1 °C/W	16.3	21	А				

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES UNIT								
I _{F(AV)}	Sinusoidal waveform	20	А					
V_{RRM}		800/1200	V					
I _{FSM}		300	А					
V _F	20 A, T _J = 25 °C	1.1	V					
T _J		-40 to +150	°C					

VOLTAGE RATINGS									
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA						
VS-20ETS08S-M3	800	900	1						
VS-20ETS12S-M3	1200	1300	'						

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum average forward current	I _{F(AV)}	T _C = 105 °C, 180° conduction half sine wave	20						
Maximum peak one cycle	l	10 ms sine pulse, rated V _{RRM} applied	250	А					
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	300						
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	316	A ² s					
waximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	442						
Maximum I ² √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s					

VS-20ETS08S-M3, VS-20ETS12S-M3 Series

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ELECTRICAL SPECIFICATIONS										
PARAMETER SYMBOL TEST CONDITIONS VALUES U										
Maximum forward voltage drop	V_{FM}	20 A, T _J = 25 °C	1.1	V						
Forward slope resistance	r _t	T _{.1} = 150 °C	10.4	mΩ						
Threshold voltage	V _{F(TO)}	1j = 150 C	0.85	V						
Maximum reverse leakage current		T _J = 25 °C	$V_{B} = Rated V_{BBM}$	0.1	mA					
waxiiiluiii ieveise leakage cuifelii	IRM	T _J = 150 °C	VR = nateu VRRM	1.0	IIIA					

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temper	erature range	T _J , T _{Stg}		-40 to +150	°C				
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	1.3					
Maximum thermal resistance, junction to ambient		R _{thJA} (1)	For D ² PAK version	62	°C/W				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.5					
Approximate weight				2	g				
Approximate weight				0.07	OZ.				
Manuality and a second minimum				6.0 (5.0)	kgf · cm				
Mounting torque –	maximum			12 (10)	(lbf \cdot in)				
Marking device			Case style D ² PAK (TO-263AB)	20ETS08S					
			Case style D-FAR (10-203AB)	20ETS12S					

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

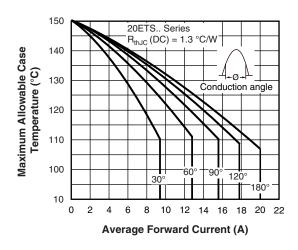


Fig. 1 - Current Rating Characteristics

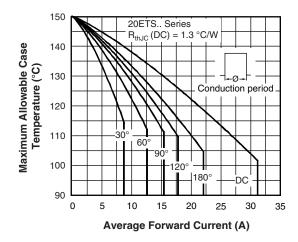


Fig. 2 - Current Rating Characteristics

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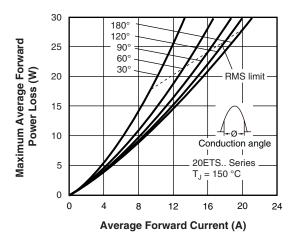


Fig. 3 - Forward Power Loss Characteristics

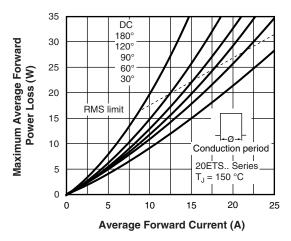


Fig. 4 - Forward Power Loss Characteristics

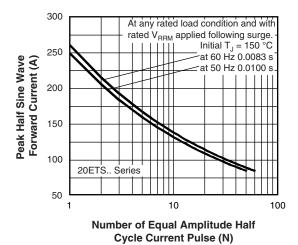


Fig. 5 - Maximum Non-Repetitive Surge Current

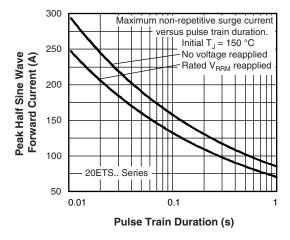


Fig. 6 - Maximum Non-Repetitive Surge Current

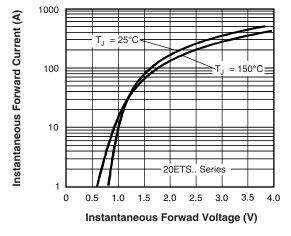


Fig. 7 - Forward Voltage Drop Characteristics

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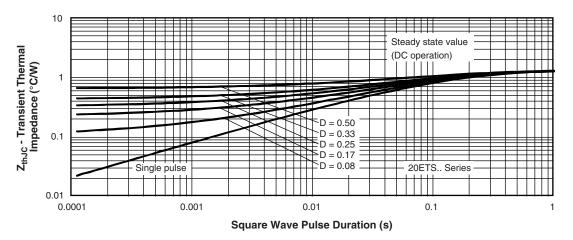
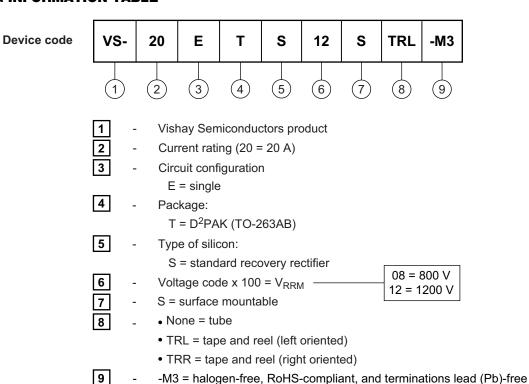


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE





VS-20ETS08S-M3, VS-20ETS12S-M3 Series

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ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-20ETS08S-M3	50	Antistatic plastic tube						
VS-20ETS08STRR-M3	800	13" diameter reel						
VS-20ETS08STRL-M3	800	13" diameter reel						
VS-20ETS12S-M3	50	Antistatic plastic tube						
VS-20ETS12STRR-M3	800	13" diameter reel						
VS-20ETS12STRL-M3	800	13" diameter reel						

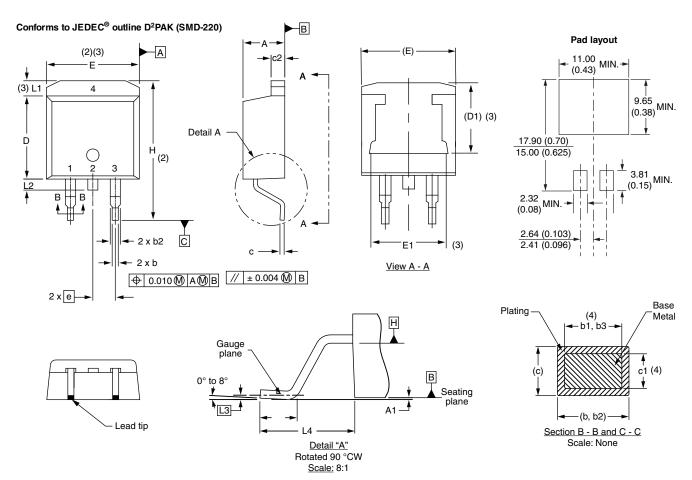
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96164			
Part marking information	www.vishay.com/doc?95444			
Packaging information	www.vishay.com/doc?96424			
SPICE model	www.vishay.com/doc?97266			



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	INCHES		NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

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